

# Pch -30V -3.5A Power MOSFET

$V_{DSS}$	-30V
$R_{DS(on)}(Max.)$	50m $Ω$
I <sub>D</sub>	-3.5A
$P_D$	1.0W

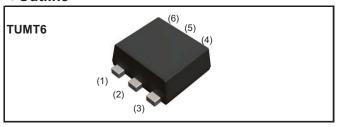
#### Features

- 1) Low on resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small Surface Mount Package (TUMT6).
- 4) Pb-free lead plating; RoHS compliant
- 5) AEC-Q101 Qualified

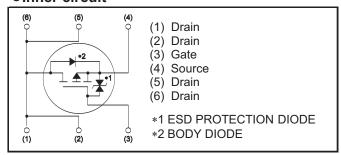
# Application

DC/DC converters

#### Outline



# •Inner circuit



Packaging specifications

	Packaging	Taping
	Reel size (mm)	180
Type	Tape width (mm)	8
Туре	Basic ordering unit (pcs)	3,000
	Taping code	TR
	Marking	UF

# ● Absolute maximum ratings(T<sub>a</sub> = 25°C)

Parameter	Symbol	Value	Unit
Drain - Source voltage	$V_{ extsf{DSS}}$	-30	V
Continuous drain current	I <sub>D</sub> *1	±3.5	А
Pulsed drain current	I <sub>D,pulse</sub> *2	±14	А
Gate - Source voltage	$V_{GSS}$	±20	V
Power dissipation	P <sub>D</sub> *3	1.0	W
Power dissipation	P <sub>D</sub> *4	0.32	W
Junction temperature	T <sub>j</sub>	150	°C
Range of storage temperature	T <sub>stg</sub>	−55 to +150	°C

# ●Thermal resistance

Parameter	Symbol	Values			Unit
raiametei	Symbol	Min.	Тур.	Max.	Offic
Thermal resistance, junction - ambient	R <sub>thJA</sub> *3	-	-	125	°C/W
Thermal resistance, junction - ambient	R <sub>thJA</sub> *4	-	-	391	°C/W

# •Electrical characteristics( $T_a = 25$ °C)

Parameter	Symbol Conditions -		Values			Unit	
r al allietei	Symbol	Conditions	Min.	Тур.	Max.	Offic	
Drain - Source breakdown voltage	V <sub>(BR)DSS</sub>	$V_{GS} = 0V$ , $I_D = -1mA$	-30	-	-	V	
		I <sub>D</sub> = -1mA referenced to 25°C	1	-25	1	mV/°C	
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{DS} = -30V, V_{GS} = 0V$	-	-	-1	μА	
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±10	μА	
Gate threshold voltage	V <sub>GS (th)</sub>	$V_{DS} = -10V, I_{D} = -1mA$	-1.0	-	-2.5	V	
Gate threshold voltage temperature coefficient	$\frac{\Delta V_{(GS)th}}{\Delta T_{j}}$	I <sub>D</sub> =b -1mA referenced to 25°C	-	3.9	-	mV/°C	
		$V_{GS} = -10V, I_D = -3.5A$	-	36	50		
Static drain - source	D *5	$V_{GS} = -4.5V, I_D = -1.7A$	-	52	72	m()	
on - state resistance	$R_{DS(on)}$	$V_{GS} = -4.0V, I_D = -1.7A$	-	58	81	mΩ	
		V <sub>GS</sub> = -10V, I <sub>D</sub> = -3.5A, T <sub>j</sub> =125°C	-	52	73		
Gate input resistannce	R <sub>G</sub>	f = 1MHz, open drain	-	19	-	Ω	
Transconductance	<b>9</b> fs *5	$V_{DS} = -10V, I_{D} = -3.5A$	2.3	6.5	-	S	

<sup>\*1</sup> Limited only by maximum temperature allowed.

<sup>\*2</sup> Pw  $\leq 10 \mu s, \, Duty \, cycle \leq 1\%$ 

<sup>\*3</sup> Mounted on a ceramic board (30×30×0.8mm)

<sup>\*4</sup> Mounted on a FR4 (15×20×0.8mm)

<sup>\*5</sup> Pulsed

# ●Electrical characteristics(T<sub>a</sub> = 25°C)

Parameter	Symbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	800	-	
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = -10V	-	120	-	pF
Reverse transfer capacitance	$C_{rss}$	f = 1MHz	-	110	-	
Turn - on delay time	$t_{d(on)}^{*5}$	$V_{DD} \simeq -15V$ , $V_{GS} = -10V$	-	7	-	
Rise time	t <sub>r</sub> *5	I <sub>D</sub> = -1.7A	-	9	-	no
Turn - off delay time	t <sub>d(off)</sub> *5	$R_L = 8.8\Omega$	-	75	-	ns
Fall time	t <sub>f</sub> *5	$R_G = 10\Omega$	-	40	-	

# •Gate Charge characteristics( $T_a = 25$ °C)

Parameter	Symbol	Conditions	Values			Unit
r ai ai nietei	Symbol	Conditions	Min.	Тур.	Max.	Offic
Total gate charge	Q <sub>a</sub> *5	$V_{DD} \simeq -15V, I_D = -3.5A$ $V_{GS} = -5V$	ı	8.0	-	
Total gate charge		$V_{DD} \simeq -15V, I_D = -3.5A$ $V_{GS} = -10V$	-	14	-	nC
Gate - Source charge	Q <sub>gs</sub> *5	$V_{DD} \simeq -15V, I_{D} = -3.5A$	1	2.5	-	
Gate - Drain charge	Q <sub>gd</sub> *5	$V_{GS} = -5V$	-	3.0	-	

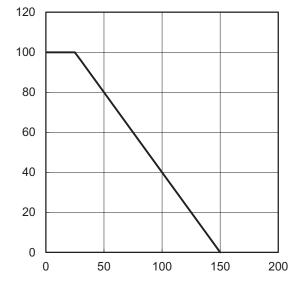
# ●Body diode electrical characteristics (Source-Drain)(T<sub>a</sub> = 25°C)

Parameter	Symbol Conditions -		Values			Unit
r ai ai i letei			Min.	Тур.	Max.	Offic
Inverse diode continuous, forward current	I <sub>S</sub> *1	T <sub>a</sub> = 25°C	-	-	-0.8	А
Forward voltage	V <sub>SD</sub> *5	$V_{GS} = 0V, I_s = -3.5A$	-	-	-1.2	V

Power Dissipation: P<sub>D</sub>/P<sub>D</sub> max. [%]

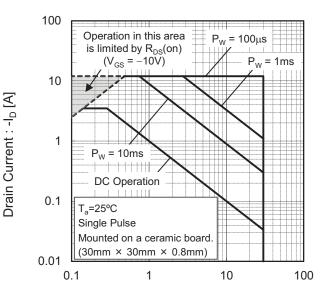
# •Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve



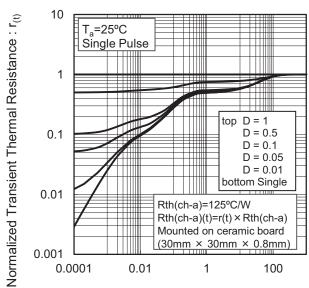
Junction Temperature : Tj [°C]

Fig.2 Maximum Safe Operating Area



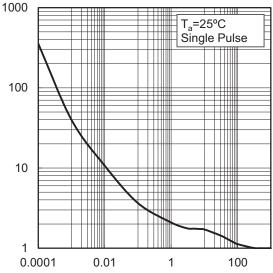
Drain - Source Voltage : -V<sub>DS</sub> [V]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



Pulse Width: Pw [s]

Fig.4 Single Pulse Maxmum Power dissipation



Pulse Width: P<sub>W</sub> [s]

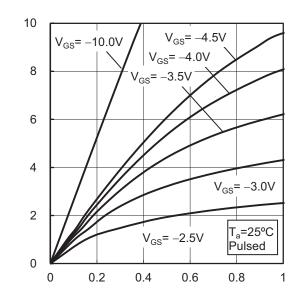
Peak Transient Power: P(W)

Drain Current: -I<sub>D</sub> [A]

Drain - Source Breakdown Voltage : - $V_{(BR)DSS}$  [V]

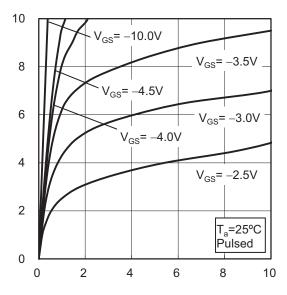
# •Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)



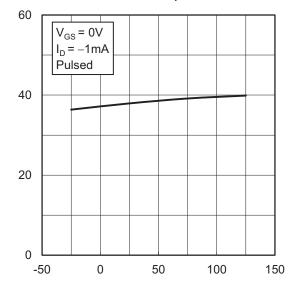
Drain - Source Voltage : -V<sub>DS</sub> [V]

Fig.6 Typical Output Characteristics(II)



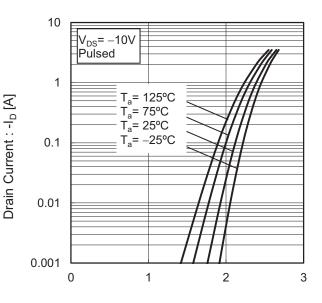
Drain - Source Voltage : -V<sub>DS</sub> [V]

Fig.7 Breakdown Voltage vs. Junction Temperature



Junction Temperature :  $T_j$  [°C]

Fig.8 Typical Transfer Characteristics



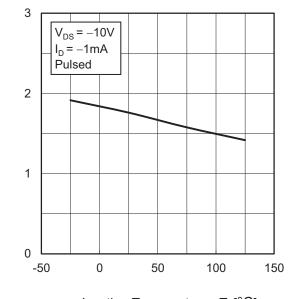
Gate - Source Voltage : -V<sub>GS</sub> [V]

Drain Current: -I<sub>D</sub> [A]

Gate Threshold Voltage: -VGS(th) [V]

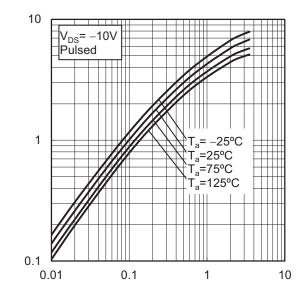
#### •Electrical characteristic curves

Fig.9 Gate Threshold Voltage vs. Junction Temperature



Transconductance : g<sub>fs</sub> [S]

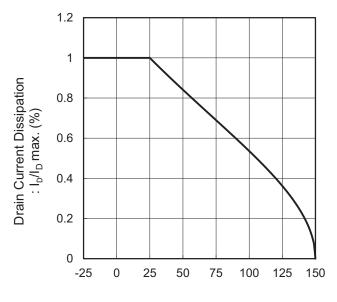
Fig.10 Transconductance vs. Drain Current



Drain Current : -I<sub>D</sub> [A]

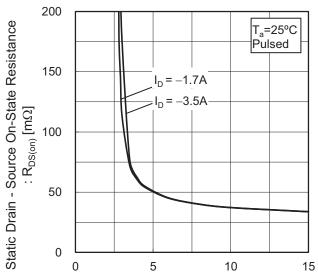
Junction Temperature :  $T_j$  [°C]

Fig.11 Drain CurrentDerating Curve



Junction Temperature : T<sub>i</sub> [°C]

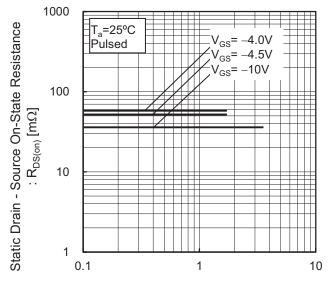
Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



Gate - Source Voltage : - $V_{GS}$  [V]

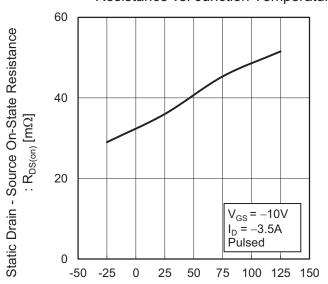
#### •Electrical characteristic curves

Fig.13 Static Drain - Source On - State Resistance vs. Drain Current(I)



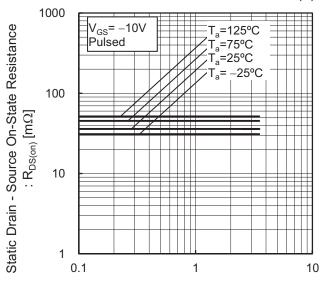
Drain Current: -ID [A]

Fig.14 Static Drain - Source On - State Resistance vs. Junction Temperature



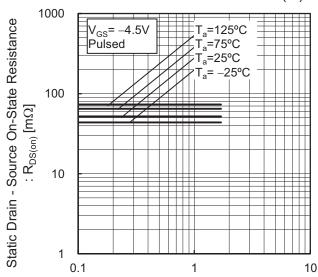
Junction Temperature : T<sub>i</sub> [°C]

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(II)



Drain Current : -I<sub>D</sub> [A]

Fig.16 Static Drain-Source On-State
Resistance vs. Drain Current(III)



Drain Current : -I<sub>D</sub> [A]

#### • Electrical characteristic curves

Fig.17 Static Drain - Source On - State Resistance vs. Drain Current(IV)

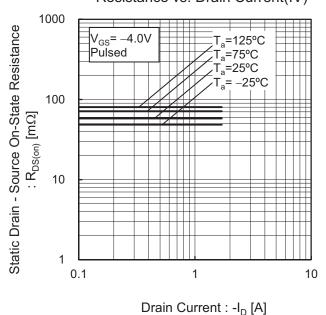
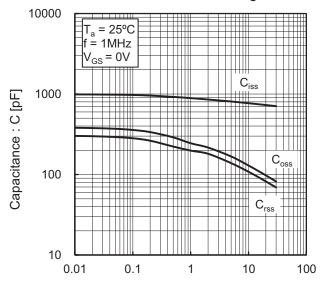


Fig.18 Typical Capacitance vs. Drain - Source Voltage



Drain - Source Voltage : -V<sub>DS</sub> [V]

Fig.19 Switching Characteristics

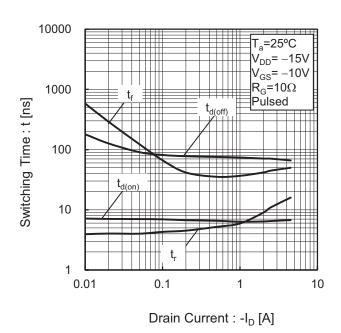
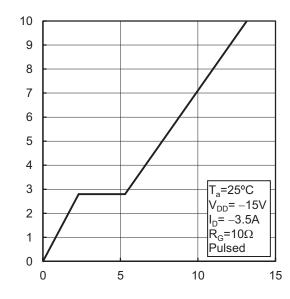


Fig.20 Dynamic Input Characteristics

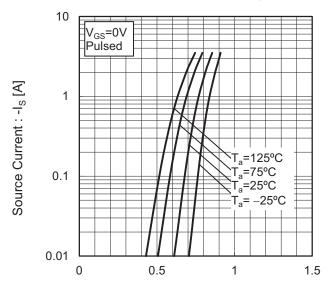


Total Gate Charge : Q<sub>q</sub> [nC]

Gate - Source Voltage : - $\mathsf{V}_{\mathsf{GS}}\left[\mathsf{V}
ight]$ 

# •Electrical characteristic curves

Fig.21 Source Current vs. Source Drain Voltage



Source-Drain Voltage :  $-V_{SD}$  [V]

# Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

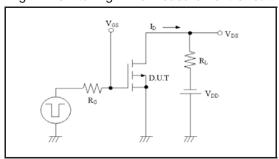


Fig.2-1 Gate Charge Measurement Circuit

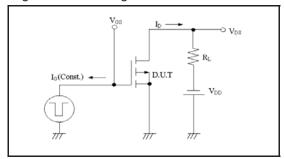


Fig.1-2 Switching Waveforms

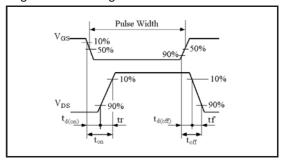
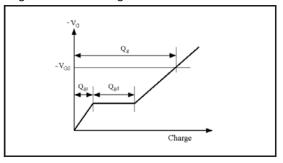
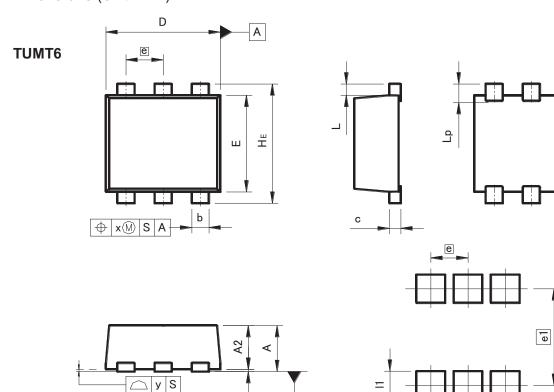


Fig.2-2 Gate Charge Waveform



# ●Dimensions (Unit : mm)



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Patterm of terminal position areas

DIM	MILIMI	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	ı	0.85	-	0.033
A1	0.00	0.10	0	0.004
A2	0.72	0.82	0.028	0.032
b	0.25	0.40	0.01	0.016
С	0.12	0.22	0.005	0.009
D	1.90	2.10	0.075	0.083
Е	1.60	1.80	0.063	0.071
е	0.0	65	0.03	
HE	2.00	2.20	0.079	0.087
L	0.3	20	0.0	01
Lp		0.40	_	0.016
х		0.10	_	0.004
У	_	0.10	_	0.004

	DIM MILIME		ETERS	INC	HES	
			MAX	MIN	MAX	
	e1	1.70		0.067		
	b2	_	0.50	_	0.02	
	l1	_	0.50	_	0.02	

Dimension in mm/inches

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1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (Note 1), aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASSⅢ	OL ACOM	CLASS II b	ОГУООШ
CLASSIV	CLASSⅢ	CLASSⅢ	CLASSⅢ

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  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - If Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### **Precautions Regarding Application Examples and External Circuits**

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### **Precaution for Storage / Transportation**

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
  may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
  exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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Notice-PAA-E Rev.003



# RRL035P03FRA - Web Page

Part Number	RRL035P03FRA
Package	TUMT6
Unit Quantity	3000
Minimum Package Quantity	3000
Packing Type	Taping
Constitution Materials List	inquiry
RoHS	Yes